

Small Signal Diode

LL4148

Features

• This is a Pb-Free and Halide Free Device

ABSOLUTE MAXIMUM RATINGS

(Values are at T_A = 25°C unless otherwise noted.) (Notes 1 and 2)

Symbol	Parameter		Value	Unit
V_{RRM}	Maximum Repetitive Reverse Voltage		100	V
I _{F(AV)}	Average Rectified	Average Rectified Forward Current		mA
I _f	Recurrent Peak Forward Current		500	mA
I _{FSM}	Non-Repetitive Peak Forward	Pulse Width = 1.0 s	1.0	Α
	Surge Current	Pulse Width = 1.0 μs	2.0	
T _{STG}	Surge Current Pulse Width = 1.0 µs Storage Temperature Range		-65 to +200	°C
TJ	Operating Junction Temperature Range		-55 to +175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. These ratings are based on a maximum junction temperature of 200°C.
- These are steady-state limits. onsemi should be consulted on applications involving pulsed or low-duty-cycle operations.

THERMAL CHARACTERISTICS

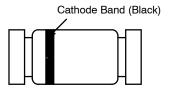
(Values are at T_A = 25°C unless otherwise noted.) (Note 3)

Symbol	Parameter	Value	Unit	
P_{D}	Power Dissipation	500	mW	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	300	°C/W	

3. JEDEC Standard 51-3 method (PCB Board size $76 \times 114 \times 0.6T$ mm³)

SOD-80 CASE 100AD

MARKING DIAGRAM



ORDERING INFORMATION

Device	Package	Shipping [†]
LL4148	SOD-80 (Pb-Free/ Halide Free)	2500 / Tape & Reel (7")

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (Values are at T_A = 25°C unless otherwise noted.)

Symbol	Parameter	Conditions	Min	Max	Unit
V _R	Breakdown Voltage	I _R = 100 μA	100	-	V
		I _R = 5.0 μA	75	-	
V _F	Forward Voltage	$I_F = 10 \text{ mA}$	-	1.0	V
I _R	Reverse Leakage	V _R = 20 V	-	25	nA
		V _R = 20 V, T _A = 150°C	-	50	μА
C _T	Total Capacitance	V _R = 0, f = 1.0 MHz	_	4.0	pF
t _{rr}	Reverse Recovery Time	I_F = 10 mA, V_R = 6.0 V (60 mA), I_{rr} = 1.0 mA, R_L = 100 Ω	-	4.0	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL PERFORMANCE CHARACTERISTICS

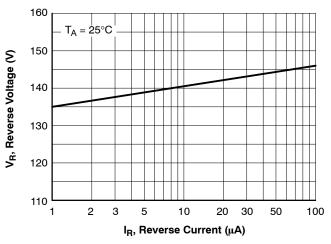


Figure 1. Reverse Voltage vs. Reverse Current BV - 1.0 to 100 μA

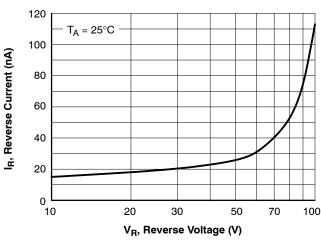


Figure 2. Reverse Voltage vs. Reverse Current I_{R} – 10 to 100 A

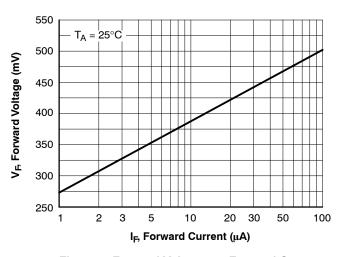


Figure 3. Forward Voltage vs. Forward Current $$V_F-1$$ to 100 μA

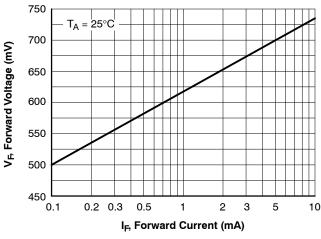


Figure 4. Forward Voltage vs. Forward Current V_F – 0.1 to 10 mA

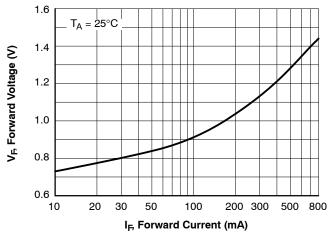


Figure 5. Forward Voltage vs. Forward Current $V_F - 10$ to 800 mA

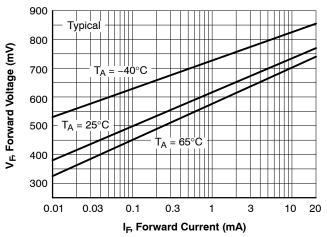
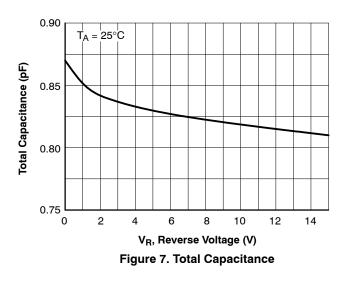


Figure 6. Forward Voltage vs. Ambient Temperature $V_F - 0.01$ to 20 mA (-40 to +65°C)

TYPICAL PERFORMANCE CHARACTERISTICS (Continued)



4.0 T_A = 25°C 3.5 3.0 2.5 2.0 1.5 1.0 10 20 30 40 50 60 I_{rr.} Reverse Recovery Current (mA)

Figure 8. Reverse Recovery Time vs.
Reverse Recovery Current

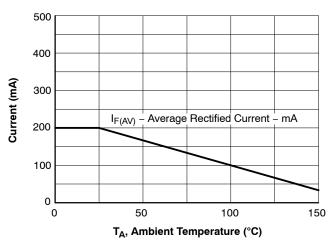


Figure 9. Average Rectified Current ($I_{F(AV)}$) vs. Ambient Temperature (T_A)

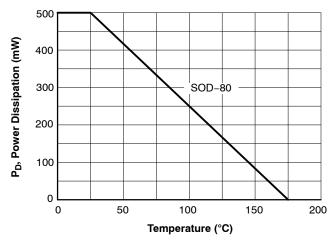
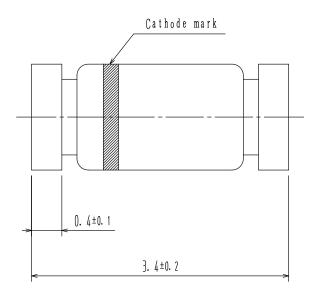


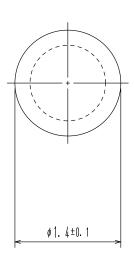
Figure 10. Power Derating Curve



MiniMELF / SOD-80 CASE 100AD ISSUE O

DATE 30 APR 2012





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